



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

CPH5901

TR : NPN Epitaxial Planar Silicon Transistor

FET : N-Channel Silicon Junction FET

High-Frequency Amplifier. AM Amplifier. Low-Frequency Amplifier Applications

Features

- Composite type with J-FET and NPN transistors contained in the CPH5 package, improving the mounting efficiency greatly
- The CPH5901 is formed with two chips, being equivalent to the 2SK932 and the other the 2SC4639, placed in one package
- Common drain and emitter

Specifications

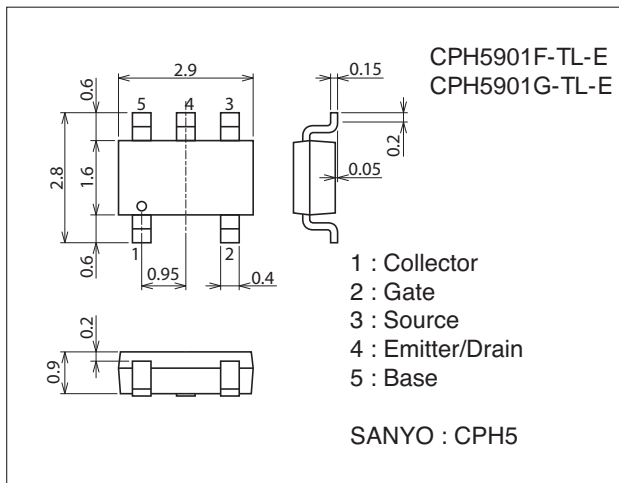
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
[FET]				
Drain-to-Source Voltage	VDSX		15	V
Gate-to-Drain Voltage	VGDS		-15	V
Gate Current	IG		10	mA
Drain Current	ID		50	mA
Allowable Power Dissipation	PD	Mounted on a ceramic board (600mm ² ×0.8mm)	350	mW
[TR]				
Collector-to-Base Voltage	VCBO		55	V
Collector-to-Emitter Voltage	VCEO		50	V
Emitter-to-Base Voltage	VEBO		6	V
Collector Current	IC		150	mA
Collector Current (Pulse)	ICP		300	mA
Base Current	IB		30	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² ×0.8mm)	350	mW
[TR]				
Total Power Dissipation	PT	Mounted on a ceramic board (600mm ² ×0.8mm)	500	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ)

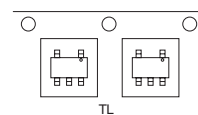
7017A-007



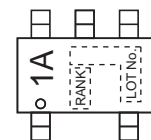
Product & Package Information

- Package : CPH5
- JEITA, JEDEC : SC-74A, SOT-25
- Minimum Packing Quantity : 3,000 pcs./reel

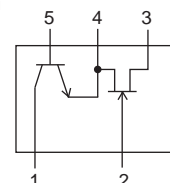
Packing Type : TL



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://semicon.sanyo.com/en/network>

CPH5901

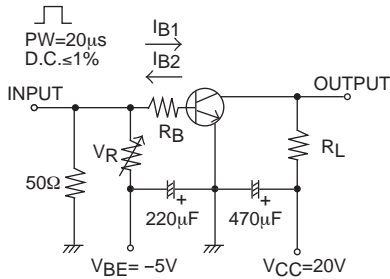
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[FET]						
Gate-to-Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A, V_{GS} = 0V$	-15			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -10V, V_{DS} = 0V$			-1.0	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 5V, I_D = 100\mu A$	-0.2	-0.6	-1.4	V
Drain Current	I_{DSS}	$V_{DS} = 5V, V_{GS} = 0V$	6.0*		20.0*	mA
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 5V, V_{GS} = 0V, f = 1kHz$	25	50		mS
Input Capacitance	C_{iss}	$V_{DS} = 5V, V_{GS} = 0V, f = 1kHz$		10		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 5V, V_{GS} = 0V, f = 1kHz$		3.0		pF
Noise Figure	NF	$V_{DS} = 5V, R_g = 1k\Omega, I_D = 1mA, f = 1kHz$		1.5		dB
[TR]						
Collector Cutoff Current	I_{CBO}	$V_{CB} = 35V, I_E = 0A$			0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 4V, I_C = 0A$			0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = 6V, I_C = 1mA$	135		400	
Gain-Bandwidth Product	f_T	$V_{CE} = 6V, I_C = 10mA$		200		MHz
Output Capacitance	C_{ob}	$V_{CB} = 6V, f = 1MHz$		1.7		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 50mA, I_B = 5mA$		0.08	0.4	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 50mA, I_B = 5mA$		0.8	1.0	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 10\mu A, I_E = 0A$	55			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1mA, R_{BE} = \infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu A, I_C = 0A$	6			V
Turn-On Time	t_{on}	See specified Test Circuit.		0.15		ns
Storage Time	t_{stg}			0.75		ns
Fall Time	t_f			0.20		ns

* : The CPH5901 is classified by I_{DSS} as follows : (unit : mA)

Rank	F	G
I_{DSS}	6.0 to 12.0	10.0 to 20.0

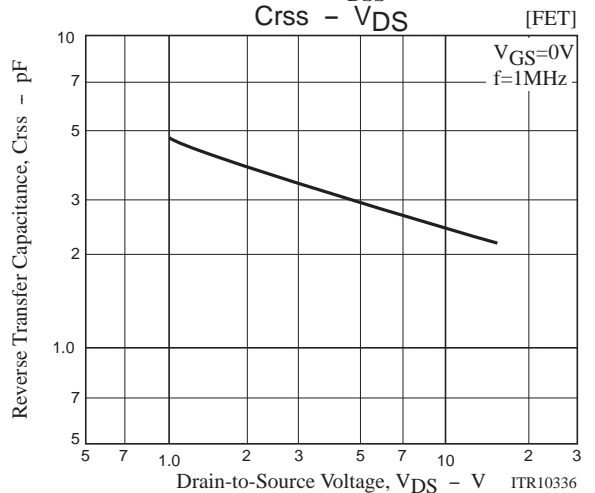
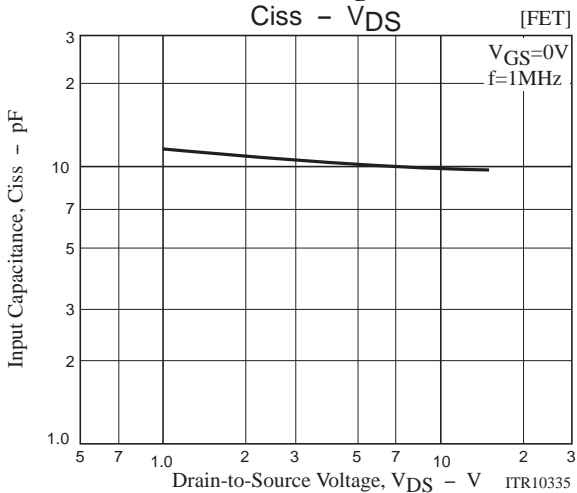
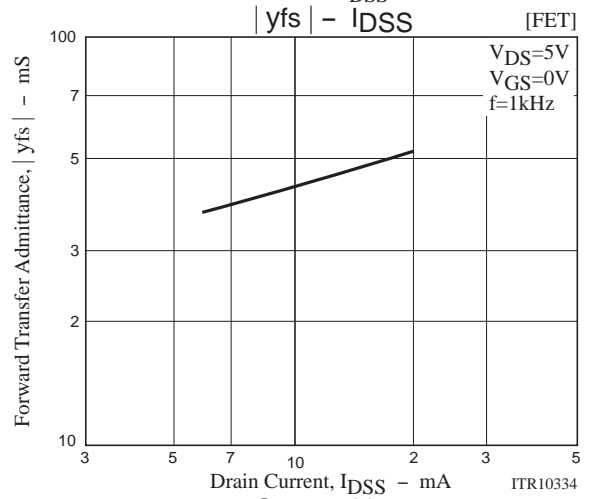
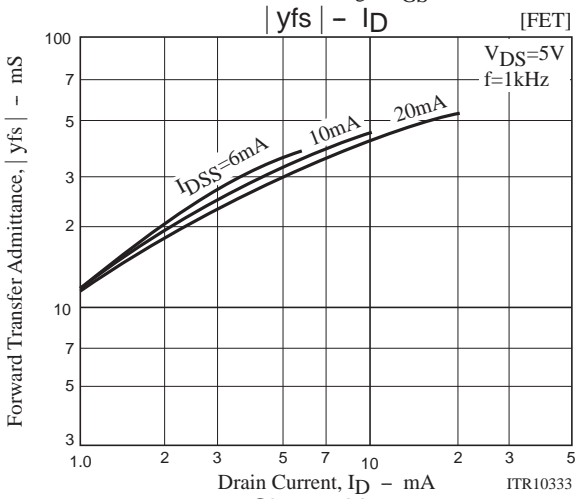
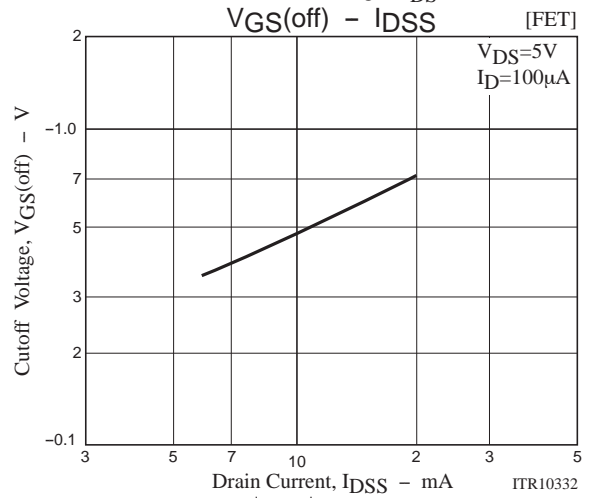
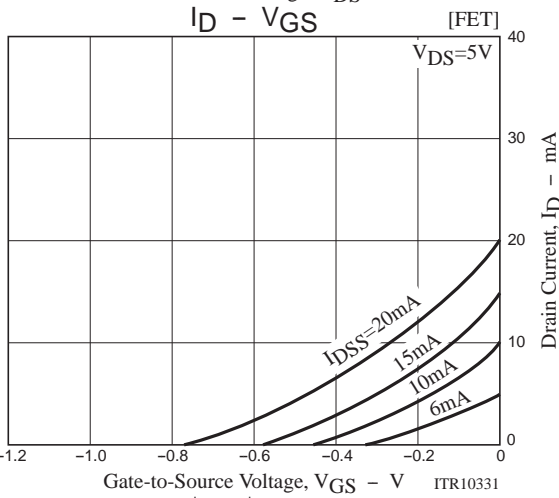
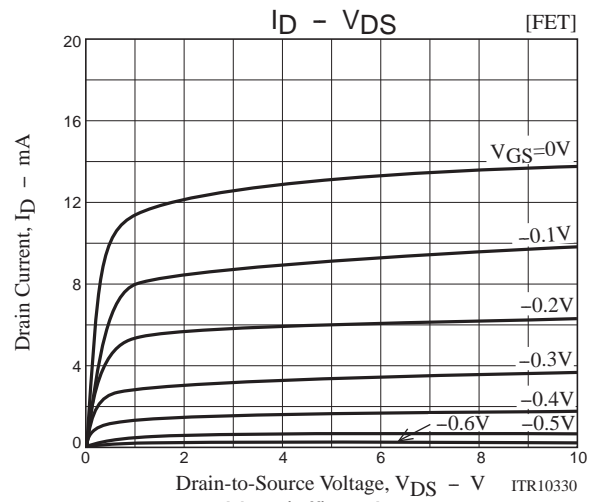
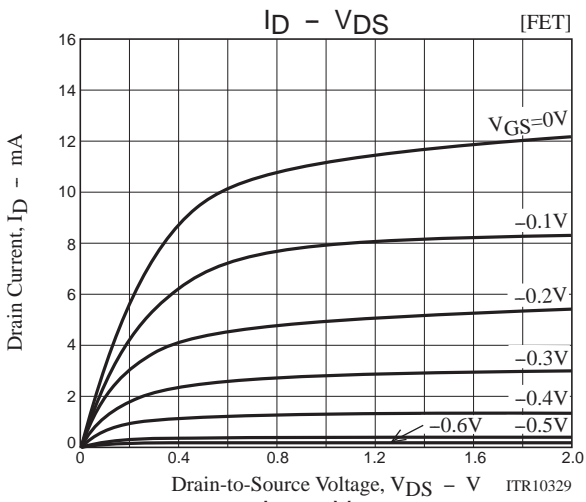
Switching Time Test Circuit



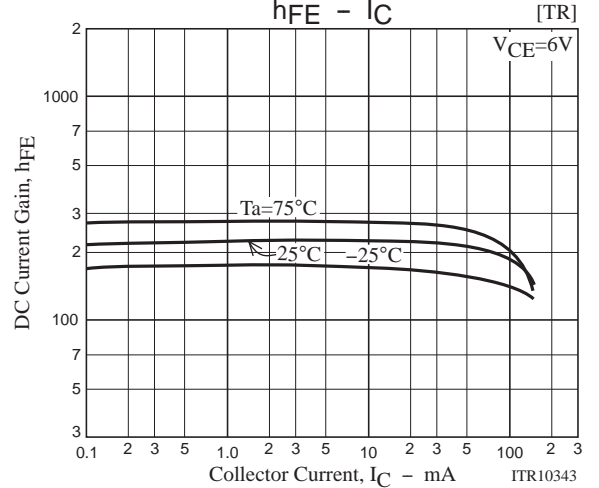
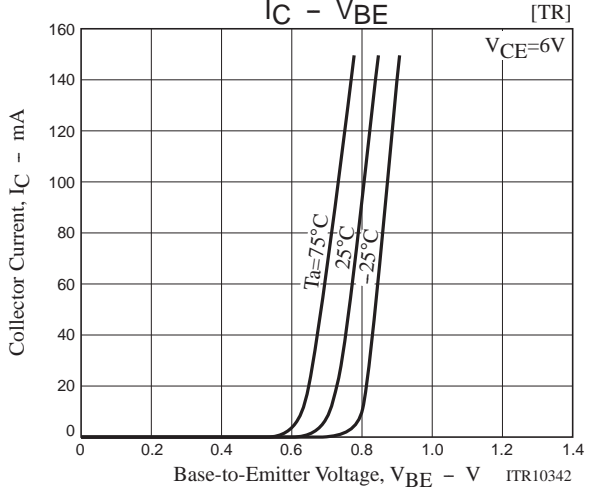
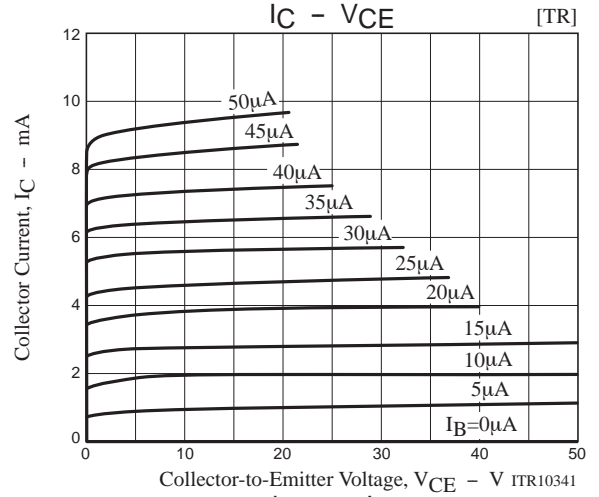
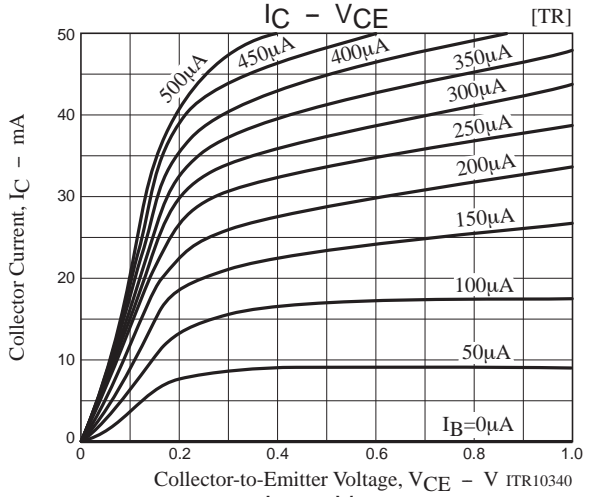
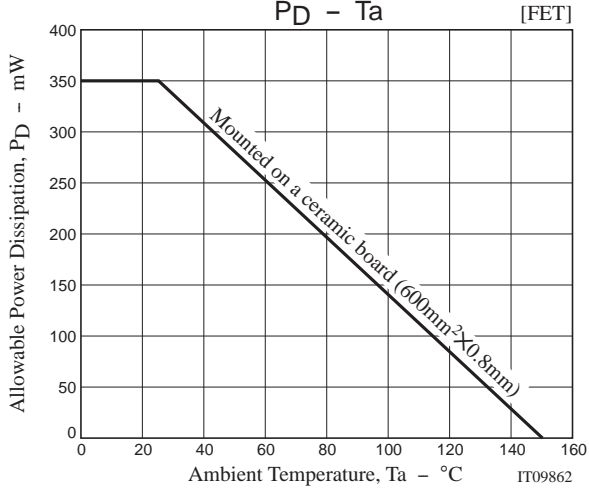
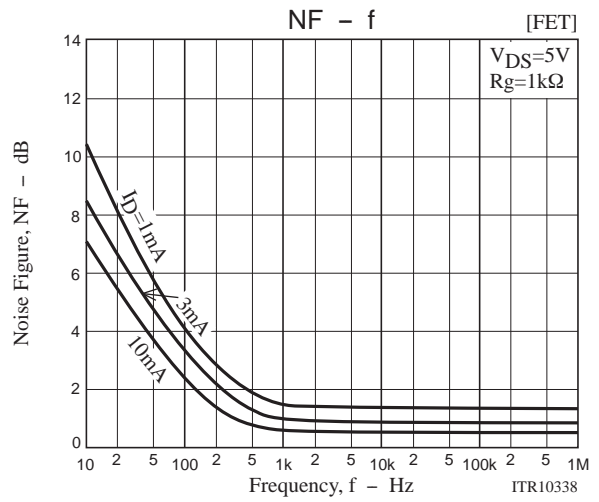
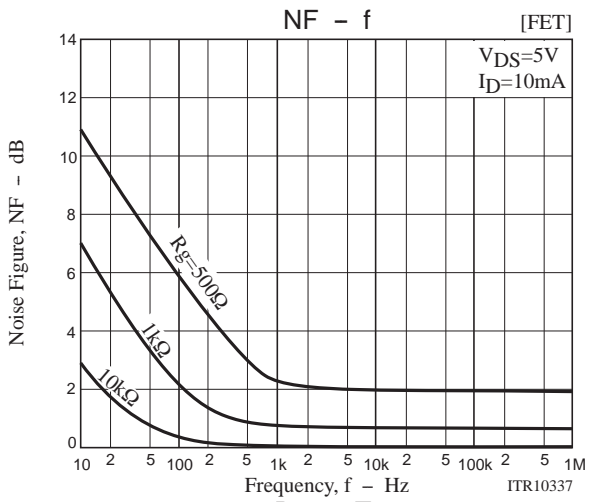
$$10I_{B1} = -10I_{B2} = I_C = 10mA$$

Ordering Information

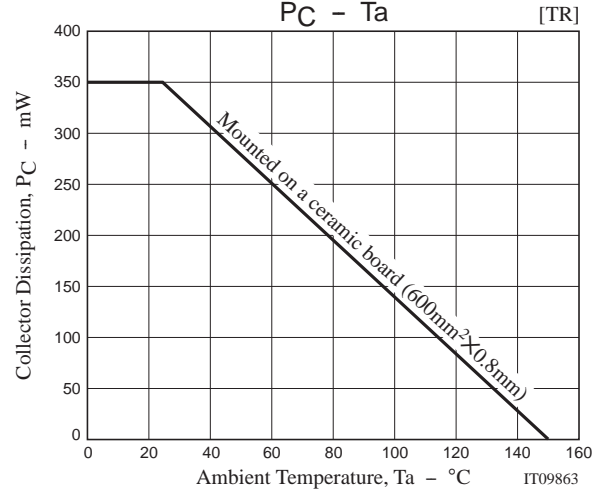
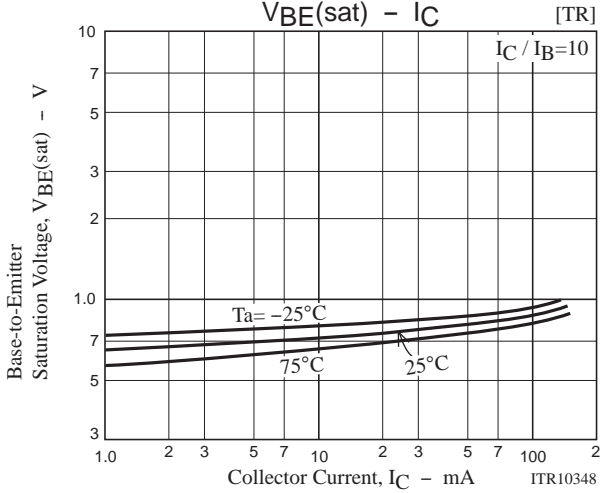
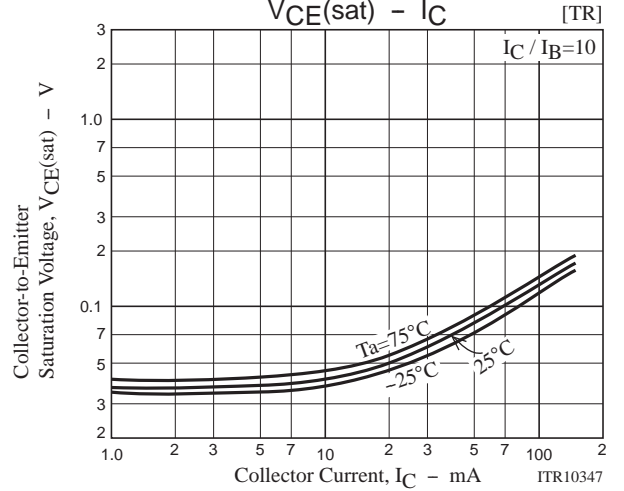
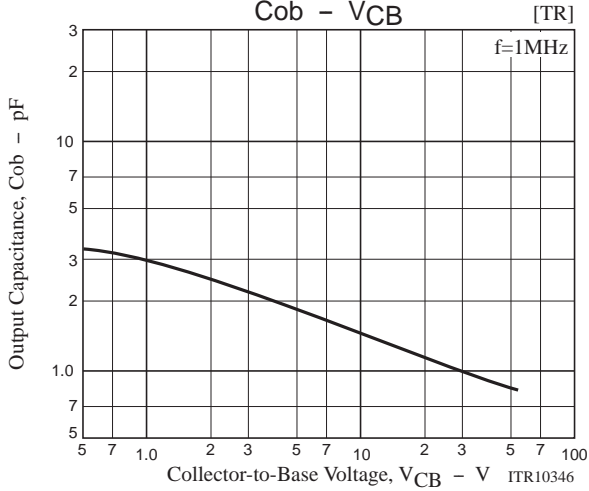
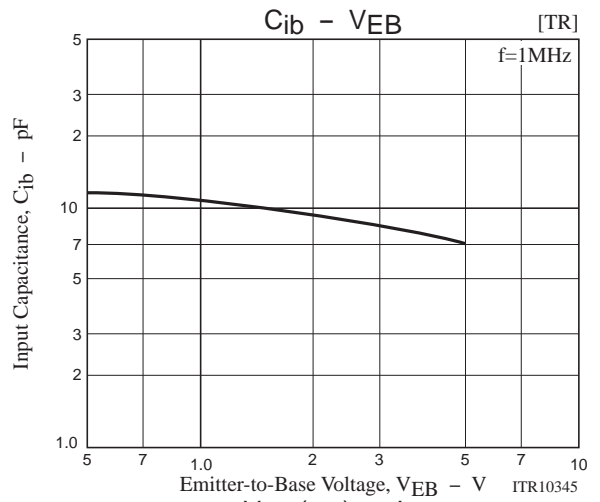
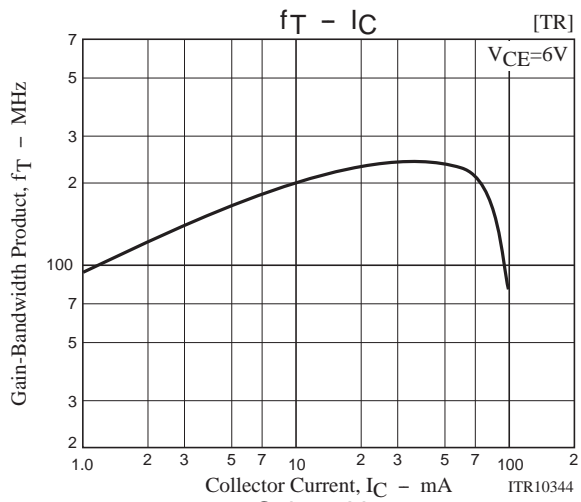
Device	Package	Shipping	memo
CPH5901F-TL-E	CPH5	3,000pcs./reel	Pb Free
CPH5901G-TL-E	CPH5	3,000pcs./reel	



CPH5901



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Embossed Taping Specification

CPH5901F-TL-E, CPH5901G-TL-E

1. Packing Format

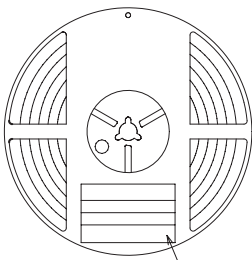
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH5	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit:mm)

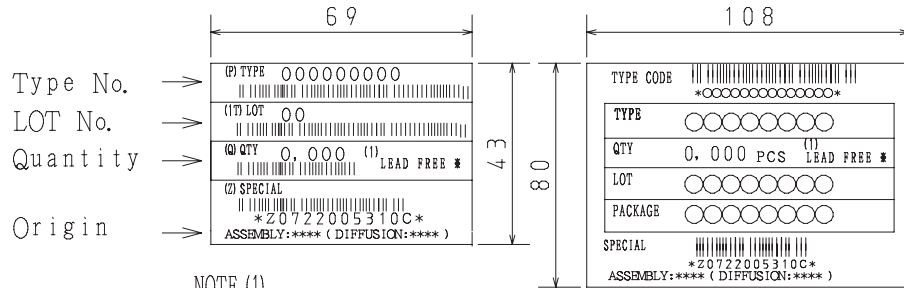
Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label



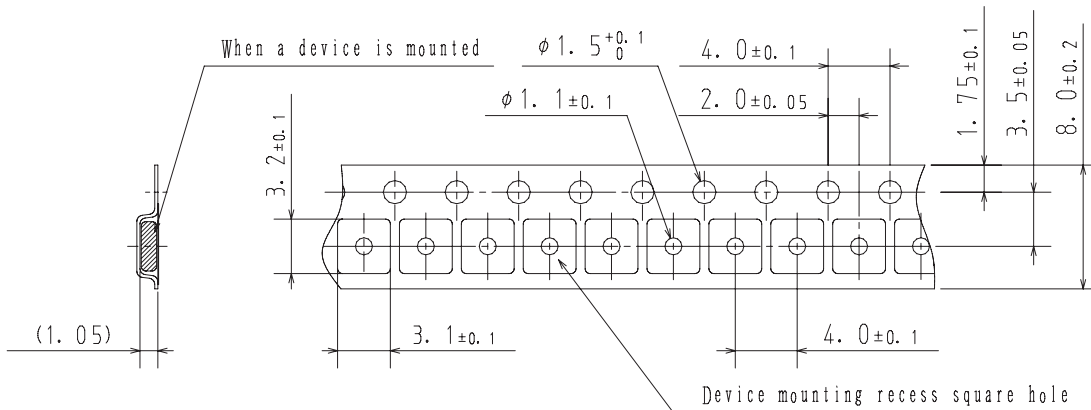
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

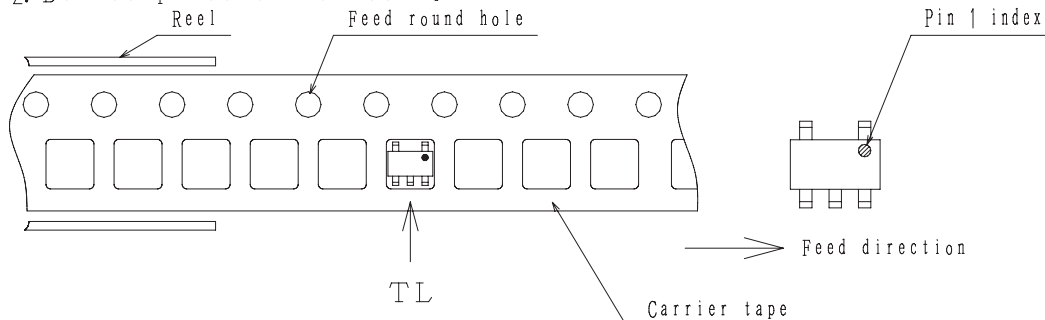
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

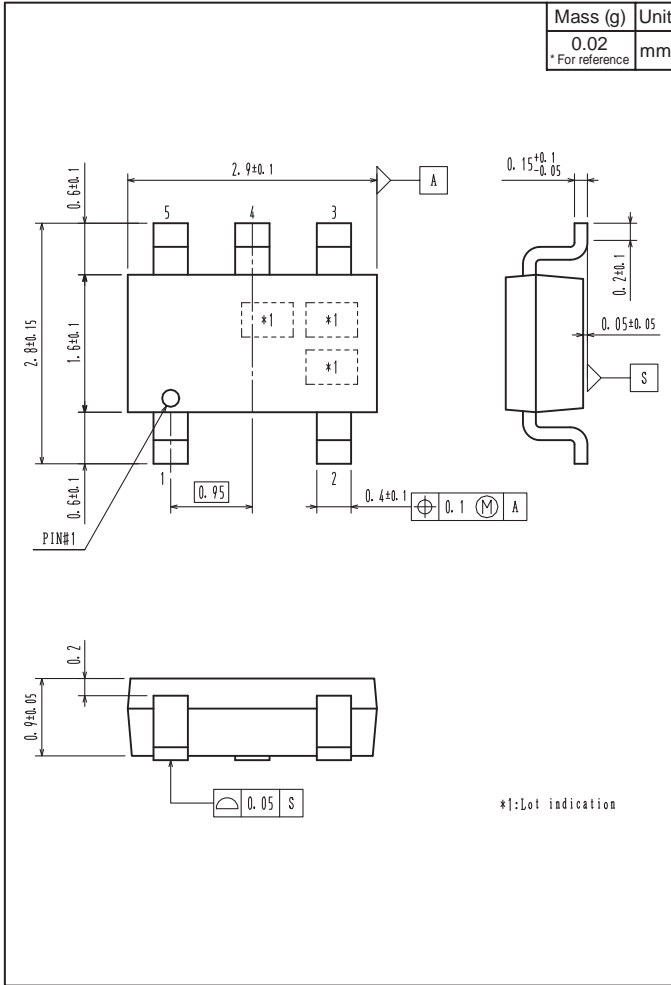


Those with pin 1 index on the feed hole side.....TL

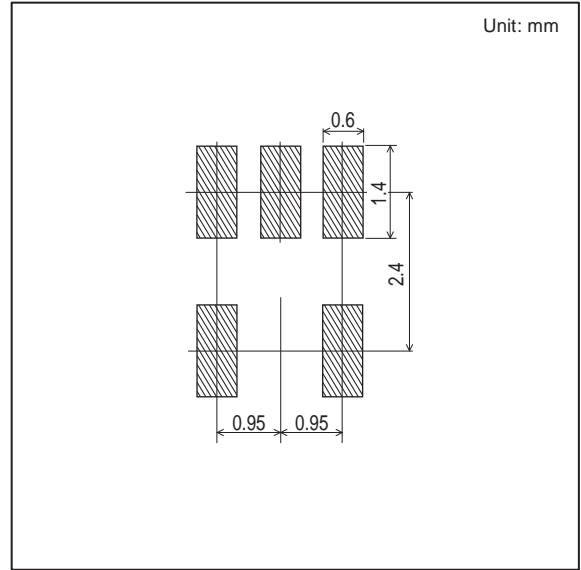
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Outline Drawing

CPH5901F-TL-E, CPH5901G-TL-E



Land Pattern Example



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